

RoHS

COMPLIANT HALOGEN

FREE Available

Vishay Siliconix

Dual P-Channel 12-V (D-S) MOSFET

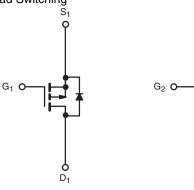
PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)		
	0.018 at V _{GS} = - 4.5 V	- 8.9		
- 12	0.022 at V _{GS} = - 2.5 V	- 8.1		
	0.028 at V _{GS} = - 1.8 V	- 3.6		

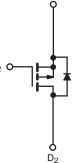


- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFET
- Advanced High Cell Density Process
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

· Load Switching

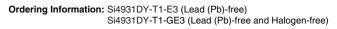




 S_2

SO-8 S_1 D_1 8 G1 7 D_1 2 S_2 6 D_2 3 G_2 D_2 4 5

Top View



P-Channel MOSFET

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_A = 25 \degree C$, unless otherwise noted					
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	- 12		V
Gate-Source Voltage		V _{GS}	± 8		
	T _A = 25 °C	– I _D	- 8.9	- 6.7	٩
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 7.1	- 5.4	
Pulsed Drain Current		I _{DM}	- 30		А
Continuous Source Current (Diode Conduction) ^a		۱ _S	- 1.7	- 0.9	
	T _A = 25 °C	PD	P. 2.0 1.1	1.1	w
Maximum Power Dissipation ^a	T _A = 70 °C		1.3	0.7	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 t	o 150	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 10 s	- R _{thJA}	46	62.5	
Maximum Junction-to-Ambient ^a	Steady State		80	110	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	24	32	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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SPECIFICATIONS $T_J = 25 \circ 0$ Parameter	Symbol			Тур.	Max.	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -350 \ \mu A$	- 0.4		- 1.0	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			± 100	nA
Zara Cata Valtaga Drain Current		V _{DS} = - 12 V, V _{GS} = 0 V			- 1	
Zero Gate Voltage Drain Current	IDSS	V_{DS} = - 12 V, V_{GS} = 0 V, T_{J} = 55 °C			- 5	μA
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 V, V_{GS} = -4.5 V$	- 30			А
	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 8.9 A		0.0145	0.018	
Drain-Source On-State Resistance ^a		V _{GS} = - 2.5 V, I _D = - 8.1 A 0.0		0.018	0.022	Ω
		V _{GS} = - 1.8 V, I _D = - 3.6 A		0.023	0.028	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 6 V, I _D = - 8.9 A		26		S
Diode Forward Voltage ^a	V _{SD}	I _S = - 1.7 A, V _{GS} = 0 V		- 0.7	- 1.2	V
Dynamic ^b						
Total Gate Charge	Qg			34.5	52	
Gate-Source Charge	Q _{gs}	V_{DS} = - 6 V, V_{GS} = - 4.5 V, I_D = - 8.9 A		5.1		nC
Gate-Drain Charge	Q _{gd}			9.6		
Gate Resistance	Rg			9		Ω
Turn-On Delay Time	t _{d(on)}			25	40	
Rise Time	t _r	V_{DD} = - 6 V, R_L = 6 Ω		46	70	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ - 1 A, V_GEN = - 4.5 V, R_g = 6 Ω		230	345	ns
Fall Time	t _f			155	235	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.7 A, dl/dt = 100 A/μs		128	200	

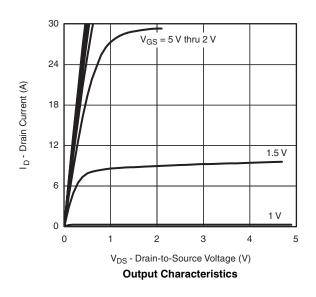
Notes:

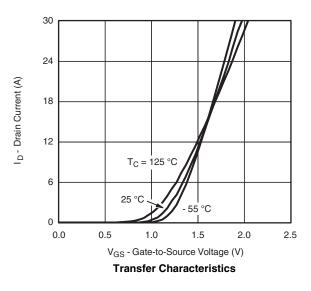
a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C unless otherwise noted

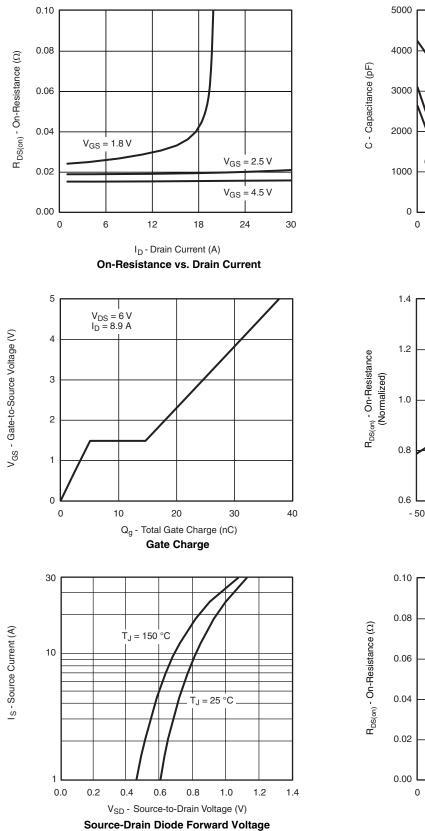


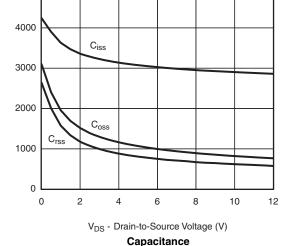


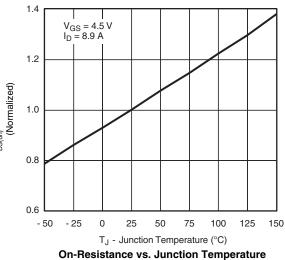
Si4931DY Vishay Siliconix

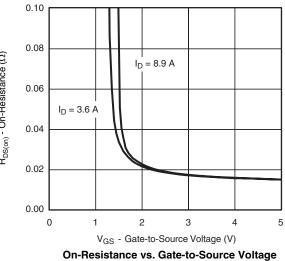
TYPICAL CHARACTERISTICS 25 °C unless otherwise noted

VISHAY







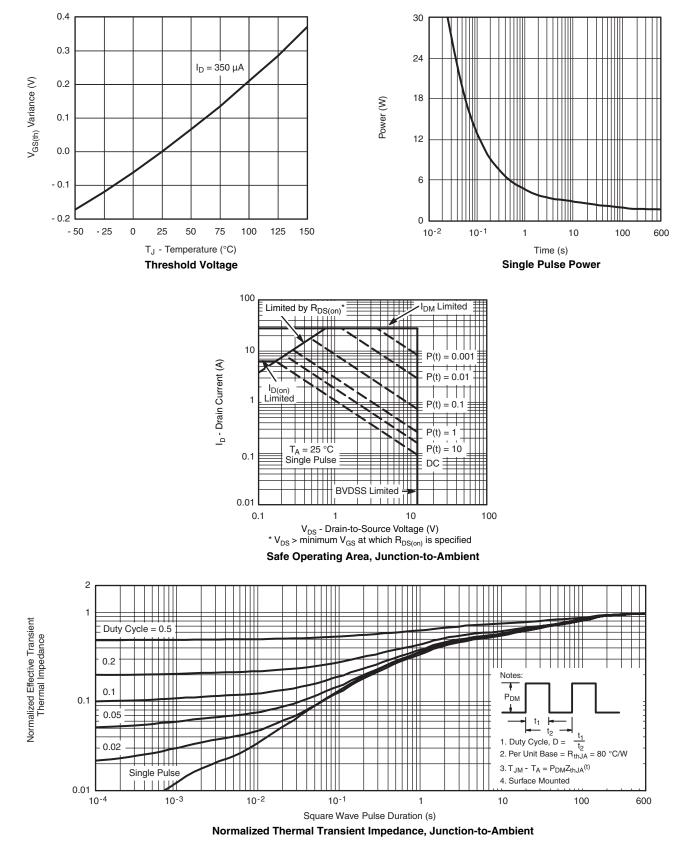


Document Number: 72379 S09-0704-Rev. C, 27-Apr-09

Si4931DY

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TYPICAL CHARACTERISTICS 25 °C unless otherwise noted



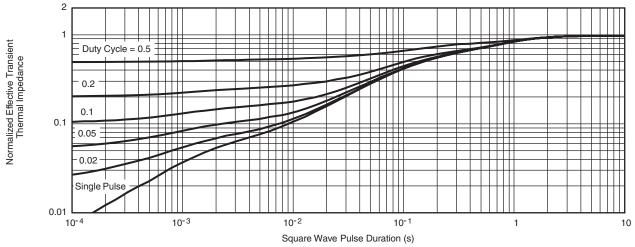
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TYPICAL CHARACTERISTICS 25 °C unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

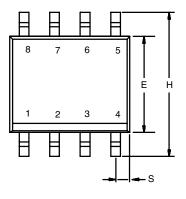
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg272379.



Package Information

Vishay Siliconix

SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





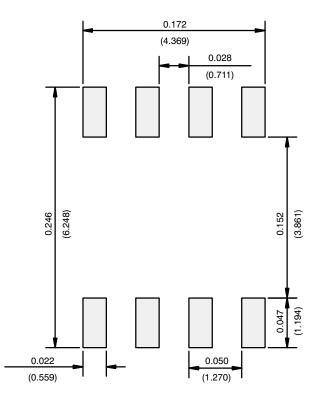
	MILLIM	IETERS	INCHES			
DIM	Min	Мах	Min	Max		
A	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498						

Application Note 826

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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